TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

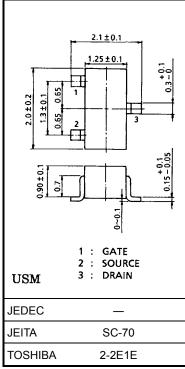
SSM3J05FU

Power Management Switch High Speed Switching Applications

- Small package
- Low on resistance : $R_{on} = 3.3 \Omega (max) (@V_{GS} = -4 V)$
 - $: R_{on} = 4.0 \Omega (max) (@V_{GS} = -2.5 V)$
- Low gate threshold voltage

Maximum Ratings (Ta = 25°C)

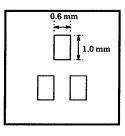
Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DS}	-20	V	
Gate-source voltage		V _{GSS}	±12	V	
Drain current	DC	ID	-200	mA	
	Pulse	I _{DP}	-400		
Drain power dissipation (Ta = 25° C)		P _D (Note 1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	



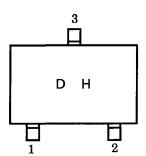
Note 1: Mounted on FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu pad: } 0.6 \text{ mm}^2 \times 3)$

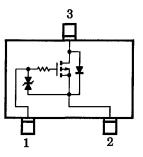
Weight: 0.006 g (typ.)



Marking



Equivalent Circuit



Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

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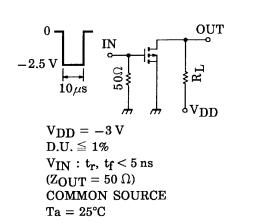
Unit: mm

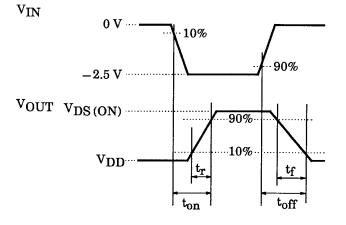
Electrical Characteristics (Ta = 25°C)

Chara	cteristics Symbol Test Condition		Min	Тур.	Max	Unit	
Gate leakage current		I _{GSS}	$V_{GS}=\pm 12~V,~V_{DS}=0$	_		±1	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = -1 \text{ mA}, V_{GS} = 0$	-20			V
Drain cut-off curre	ent	I _{DSS}	$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = 0$	—		-1	μA
Gate threshold vo	oltage	V _{th}	$V_{DS} = -3 V$, $I_D = -0.1 mA$	-0.6		-1.1	V
Forward transfer	admittance	Y _{fs}	$V_{DS} = -3 \text{ V}, \text{ I}_{D} = -50 \text{ mA}$ (Note 2)	100			mS
Drain-source ON resistance		R _{DS (ON)}	$I_D = -100 \text{ mA}, V_{GS} = -4 \text{ V}$ (Note 2)	—	2.1	3.3	Ω
			$I_D = -50 \text{ mA}, V_{GS} = -2.5 \text{ V}$ (Note 2)	—	3.2	4.0	
Input capacitance		C _{iss}	$V_{DS}=-3~V,~V_{GS}=0,~f$ = 1 MHz	_	27		pF
Reverse transfer capacitance		C _{rss}	$V_{DS}=-3~V,~V_{GS}=0,~f=1~MHz$	—	7		pF
Output capacitance		C _{oss}	$V_{DS}=-3~V,~V_{GS}=0,~f=1~MHz$	_	21		pF
Switching time	Turn-on time	t _{on}	$\begin{array}{l} V_{DD} = -3 \ V, \ I_D = -50 \ m\text{A}, \\ V_{GS} = 0 \text{\sim-2.5 V} \end{array}$	—	70		ns
	Turn-off time	t _{off}		—	70		

Note 2: Pulse test

Switching Time Test Circuit





Precaution

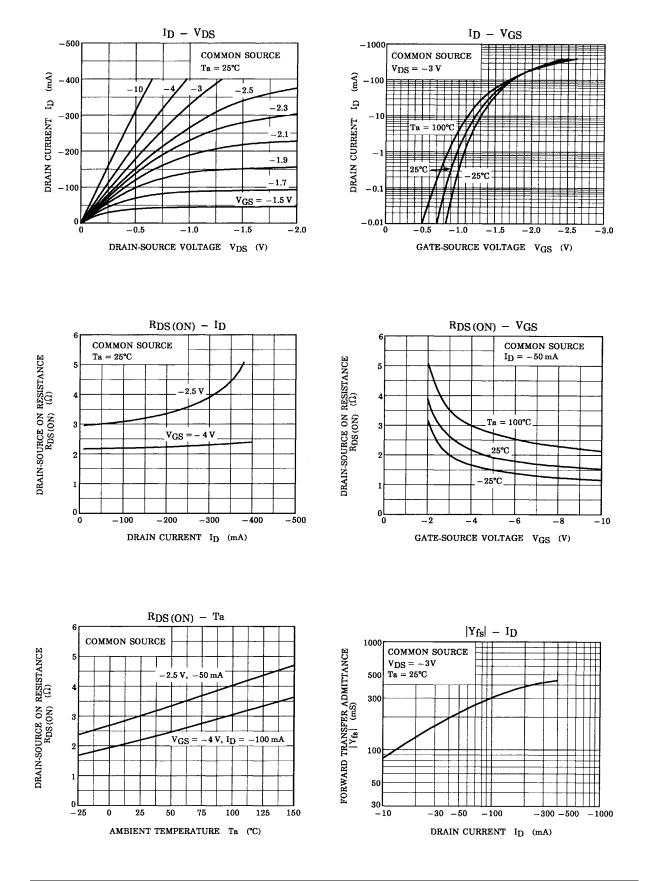
 V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = $-100~\mu A$ for this product. For normal switching operation, V_{GS} (ON) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} .

(Relationship can be established as follows: VGS (off) < Vth < VGS (ON))

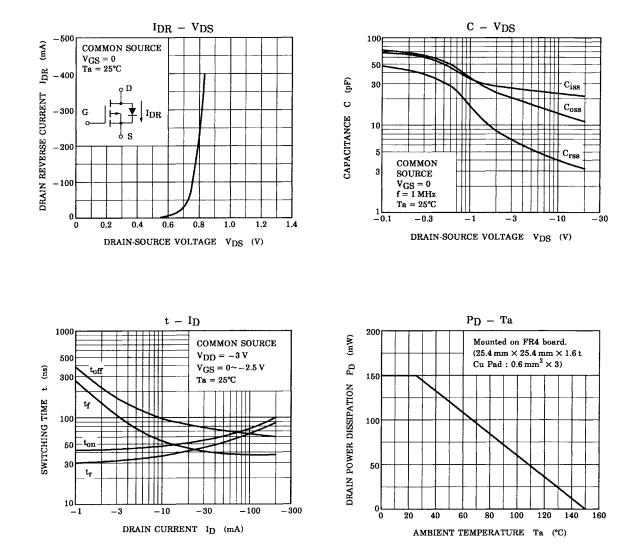
Please take this into consideration for using the device.

 $V_{\rm GS}$ recommended voltage of –2.5 V or higher to turn on this product.

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RESTRICTIONS ON PRODUCT USE

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